

Vishay Siliconix

P-Channel 8 V (D-S) MOSFET

DESCRIPTION

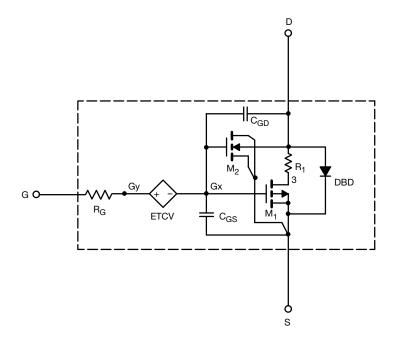
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - $55\,^{\circ}$ C to 125 $^{\circ}$ C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer
to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model Si8805EDB

Vishay Siliconix

SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	0.6	-	٧
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -1.5 \text{ A}$	0.061	0.056	Ω
		$V_{GS} = -2.5 \text{ V}, I_D = -1.5 \text{ A}$	0.077	0.070	
Forward Transconductancea	9fs	$V_{DS} = -4 V$, $I_D = -1.5 A$	8	8	S
Diode Forward Voltage	V_{SD}	I _S = - 1.5 A	- 0.74	- 0.80	V
Dynamic ^b					
Total Gate Charge	Q_g	V _{DS} = - 4 V, V _{GS} = - 4.5 V, I _D = - 1.5 A	5.3	6.7	nC
Gate-Source Charge	Q_{gs}		0.7	0.7	
Gate-Drain Charge	Q _{gd}		1.8	1.8	

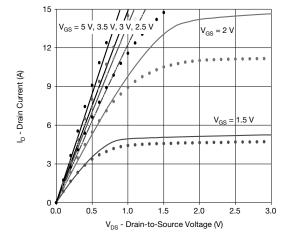
Notes

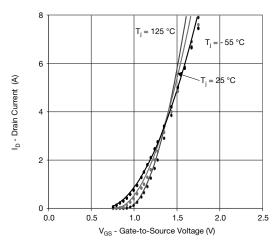
- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

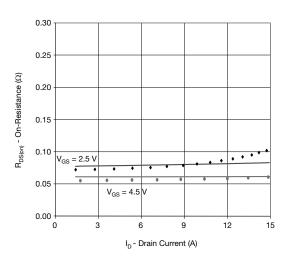
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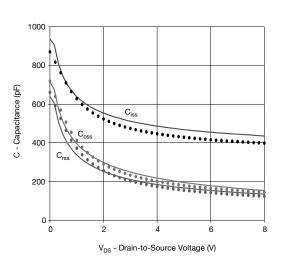
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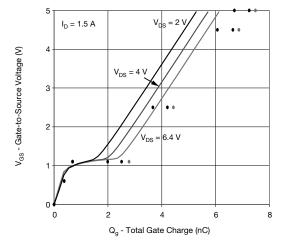
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25$ °C, unless otherwise noted)

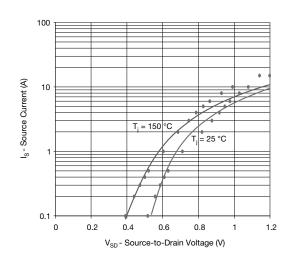












Note

· Dots and squares represent measured data.



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